



Features

- BV_{CEO} > 465V
- BV_{CES} > 700V
- $BV_{FBO} > 9V$
- I_C = 1.5A high Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Applications

Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED lighting

TO126

465V NPN HIGH VOLTAGE POWER TRANSISTOR

Mechanical Data

- Case: TO126
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 @3
- Weight: 400mg (Approximate)

В E **Device Schematic** B С Е Front Face View Pin-Out

Ordering Information (Note 4)

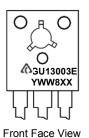
	Product	Package	Marking	Quantity				
	APT13003EU-G1	TO126	GU13003E	4000 Bulk, Loose per Box				
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.							

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds. 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



GU13003E = Product Type Marking ID YWW = Date Code Marking e.g. 312 = Year 2013, Week 12. 8 = Assembly site code XX = Batch Number



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	465	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	I _C	1.5	А
Peak Pulse Collector Current(Note 5)	I _{CM}	3	А
Continuous Base Current	IB	0.75	А
Peak Pulse Base Current(Note 5)	I _{BM}	1.5	А

Note: 5. Pulse test for pulse width < 5ms, duty cycle \leq 10%.

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

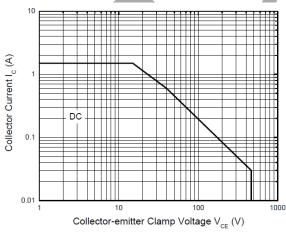
Characteristic	Symbol	Value	Unit
Power Dissipation	PD	20	W
Thermal Resistance, Junction to Ambient Air	R _{0JA}	96	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	6.25	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-65 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Note: 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Area (@T_A = +25°C, unless otherwise specified.)



Safe Operating Areas (TO-126 Package)



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

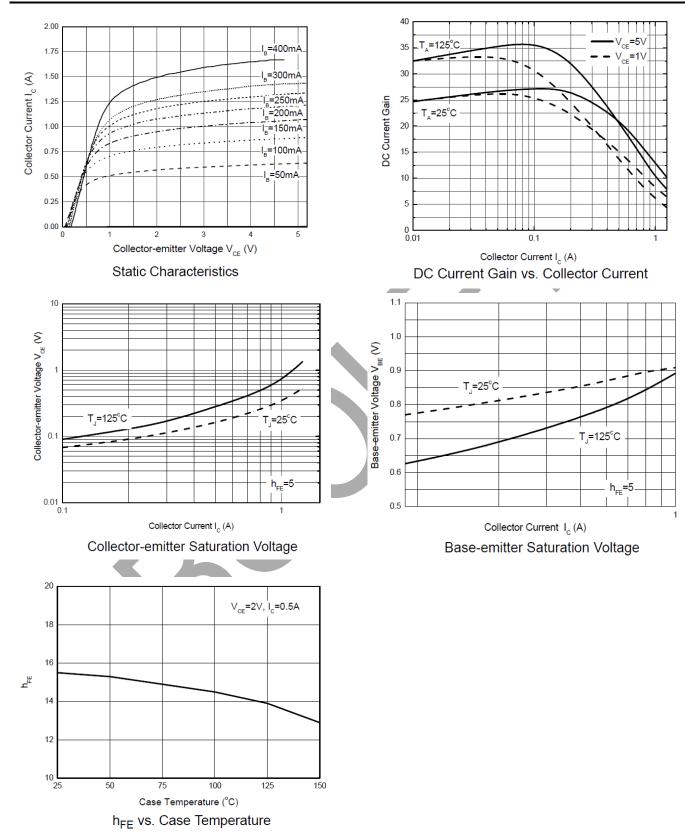
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	_	_	V	I _C = 100μA, V _{BE} = 0V
Collector-Emitter Breakdown Voltage	BV _{CEO}	465	—	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	_	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	—	—	10	μA	V _{CE} = 700V, V _{BE} = -1.5V
		15	_	_	_	I _C = 0.3A, V _{CE} = 2V
DC current transfer Static ratio (Note 7)	h _{FE}	13	17	30	—	I _C = 0.5A, V _{CE} = 2V
		5	—	25	—	I _C = 1.0A, V _{CE} = 2V
Collector Emiliar Columnian Malage (Nate 7)	V _{CE(sat)}	_	0.17	0.3	V	I _C = 0.5A, I _B = 0.1A
Collector-Emitter Saturation Voltage (Note 7)		—	0.29	0.4		I _C = 1A, I _B = 0.25A
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	—	_	1.0	V	I _C = 0.5A, I _B = 0.1A
Dase-Emilier Saturation Voltage (Note 7)		—	—	1.2		I _C = 1A, I _B = 0.25A
Output Capacitance	Cob	_	16	—	рF	$V_{CB} = 10V, f = 0.1MHz$
Transition Frequency	f⊤	4	_	-	MHz	I _C = 0.1A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	—	0.3	1		
Storage Time with Resistive Load	ts	—	1.8	3	μs	$I_{C} = 1A, V_{CC} = 125V, I_{B1} = 0.2A$
Fall Time with Resistive Load	tf	_	0.28	0.4		I _{B2} = -0.2A, t _p = 25μs

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

APT13003EU Datasheet Number: DS42589 Rev.1 - 4



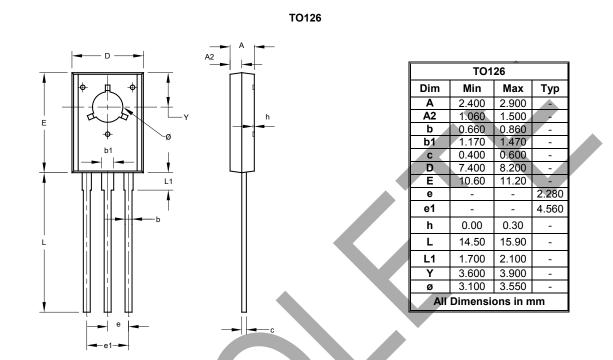
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.





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